



NPN SILICON RF TRANSISTOR

NE85633 / 2SC3356

NPN EPITAXIAL SILICON RF TRANSISTOR FOR MICROWAVE LOW-NOISE AMPLIFICATION 3-PIN MINIMOLD

FEATURES

- Low noise and high gain : $NF = 1.1 \text{ dB TYP.}$, $G_a = 11 \text{ dB TYP.}$ @ $V_{CE} = 10 \text{ V}$, $I_c = 7 \text{ mA}$, $f = 1 \text{ GHz}$
- High power gain : $MAG = 13 \text{ dB TYP.}$ @ $V_{CE} = 10 \text{ V}$, $I_c = 20 \text{ mA}$, $f = 1 \text{ GHz}$

ORDERING INFORMATION

Part Number	Quantity	Supplying Form
NE85633-A 2SC3356	50 pcs (Non reel)	• 8 mm wide embossed taping
NE85633-T1B-A 2SC3356-T1B	3 kpcs/reel	• Pin 3 (Collector) face the perforation side of the tape

Remark To order evaluation samples, contact your nearby sales office.
The unit sample quantity is 50 pcs.

ABSOLUTE MAXIMUM RATINGS ($T_A = +25^\circ\text{C}$)

Parameter	Symbol	Ratings	Unit
Collector to Base Voltage	V_{CBO}	20	V
Collector to Emitter Voltage	V_{CEO}	12	V
Emitter to Base Voltage	V_{EBO}	3.0	V
Collector Current	I_c	100	mA
Total Power Dissipation	P_{tot} ^{Note}	200	mW
Junction Temperature	T_j	150	$^\circ\text{C}$
Storage Temperature	T_{stg}	-65 to +150	$^\circ\text{C}$

Note Free air

Caution Observe precautions when handling because these devices are sensitive to electrostatic discharge.

The information in this document is subject to change without notice. Before using this document, please confirm that this is the latest version.

ELECTRICAL CHARACTERISTICS (T_A = +25°C)

Parameter	Symbol	Test Conditions	MIN.	TYP.	MAX.	Unit
DC Characteristics						
Collector Cut-off Current	I _{CBO}	V _{CB} = 10 V, I _E = 0 mA	–	–	1.0	μA
Emitter Cut-off Current	I _{EBO}	V _{EB} = 1.0 V, I _C = 0 mA	–	–	1.0	μA
DC Current Gain	h _{FE} ^{Note 1}	V _{CE} = 10 V, I _C = 20 mA	50	120	250	–
RF Characteristics						
Gain Bandwidth Product	f _T	V _{CE} = 10 V, I _C = 20 mA	–	7	–	GHz
Insertion Power Gain	S _{21e} ²	V _{CE} = 10 V, I _C = 20 mA, f = 1 GHz	–	11.5	–	dB
Noise Figure	NF	V _{CE} = 10 V, I _C = 7 mA, f = 1 GHz	–	1.1	2.0	dB
Reverse Transfer Capacitance	C _{re} ^{Note 2}	V _{CB} = 10 V, I _E = 0 mA, f = 1 MHz	–	0.55	1.0	pF

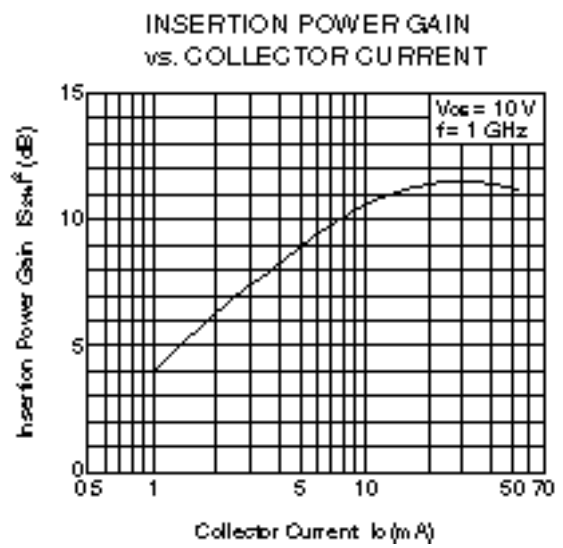
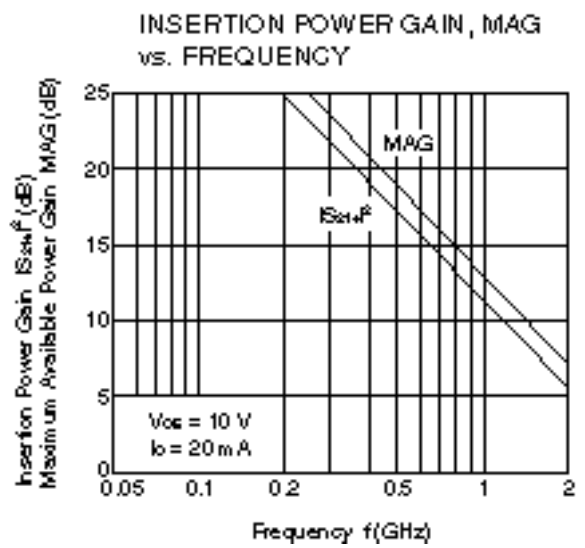
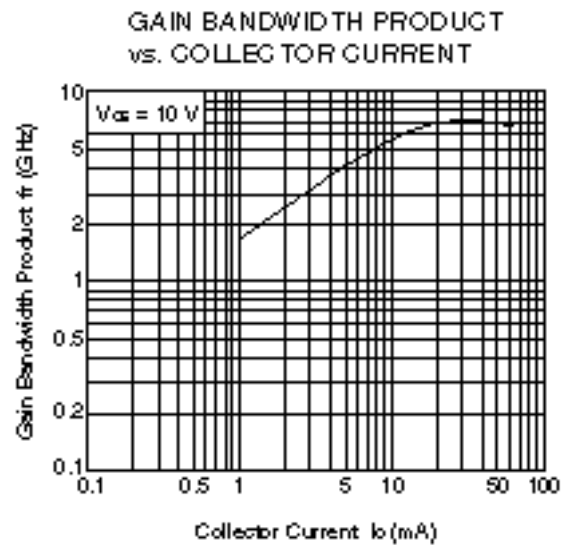
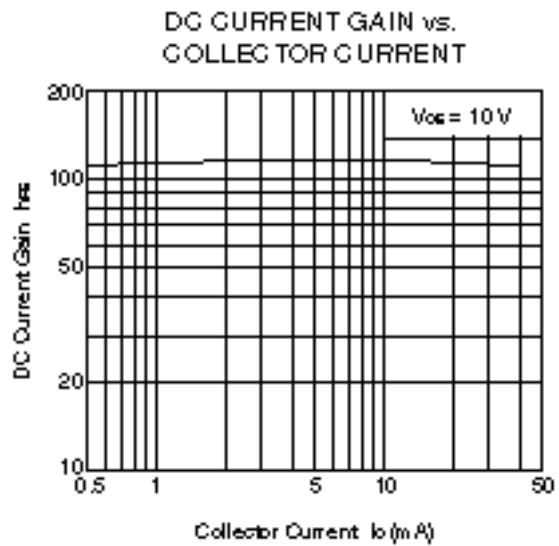
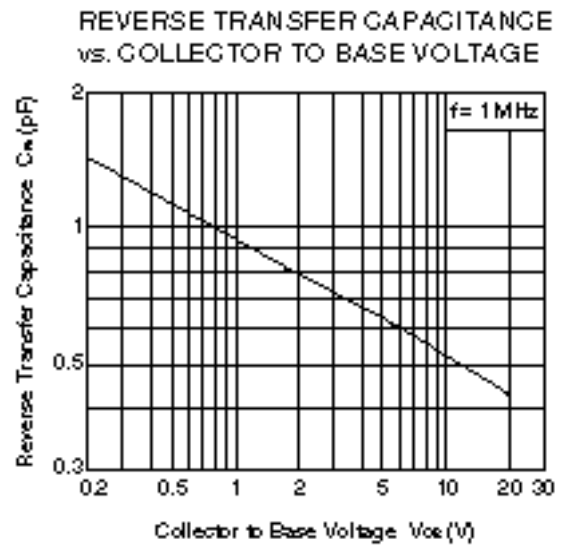
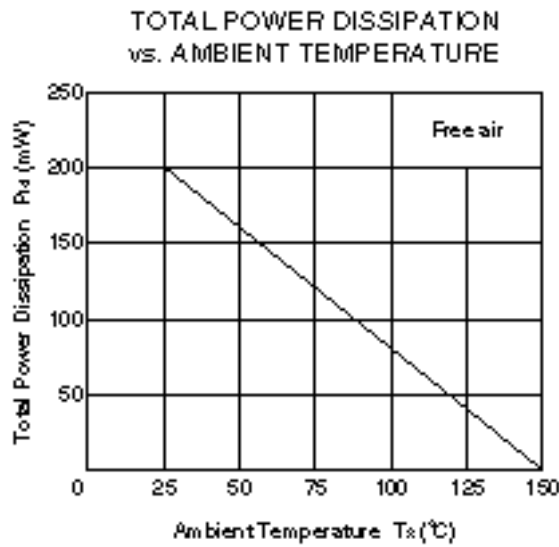
- Notes 1.** Pulse measurement: PW ≤ 350 μs, Duty Cycle ≤ 2%
2. Collector to base capacitance when the emitter grounded

h_{FE} CLASSIFICATION

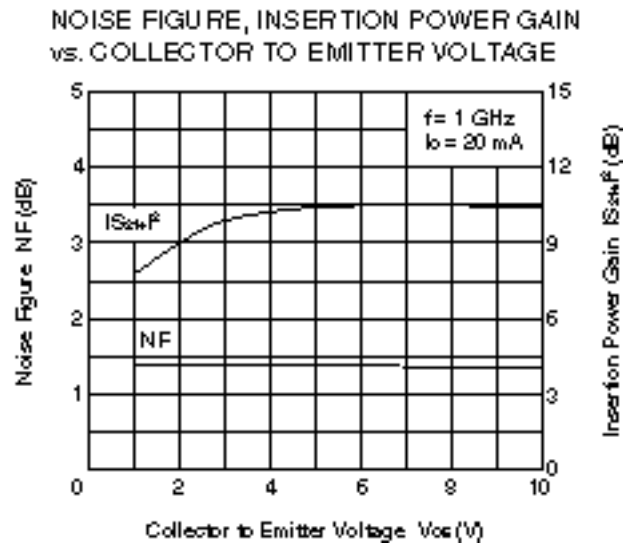
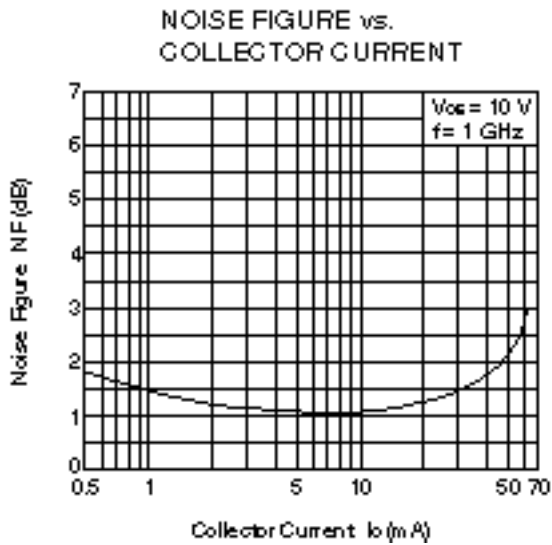
Rank	R23/Q ^{Note}	R24/R ^{Note}	R25/S ^{Note}
Marking	R23	R24	R25
h _{FE} Value	50 to 100	80 to 160	125 to 250

Note Old Specification/New Specification

TYPICAL CHARACTERISTICS (T_A = +25°C, unless otherwise specified)



Remark The graphs indicate nominal characteristics.



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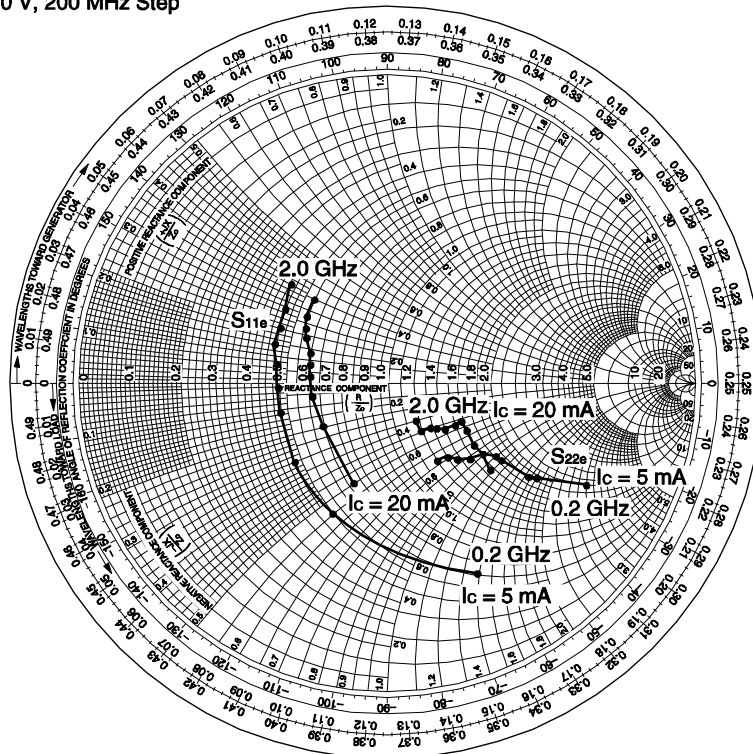
S-PARAMETERS

- S-parameters/Noise parameters are provided on the NEC Compound Semiconductor Devices Web site in a form (S2P) that enables direct import to a microwave circuit simulator without keyboard input.
- Click here to download S-parameters.
- [RF and Microwave] → [Device Parameters]
- URL <http://www.ncsd.necel.com/>

SMITH CHART

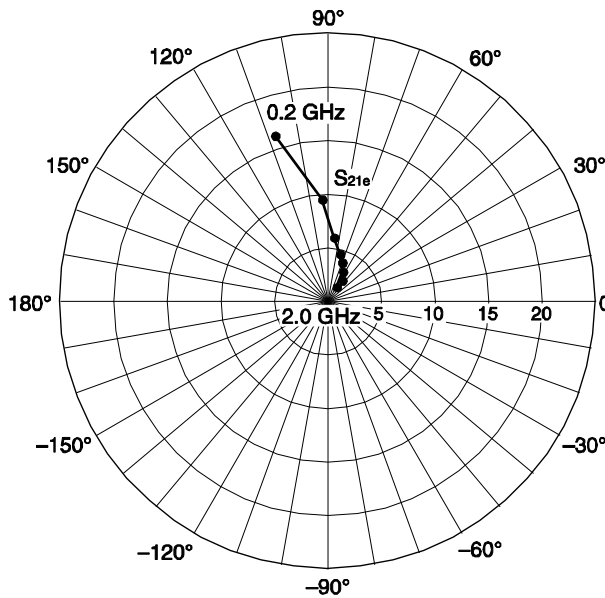
S_{11e}, S_{22e}-FREQUENCY

CONDITION : V_{CE} = 10 V, 200 MHz Step



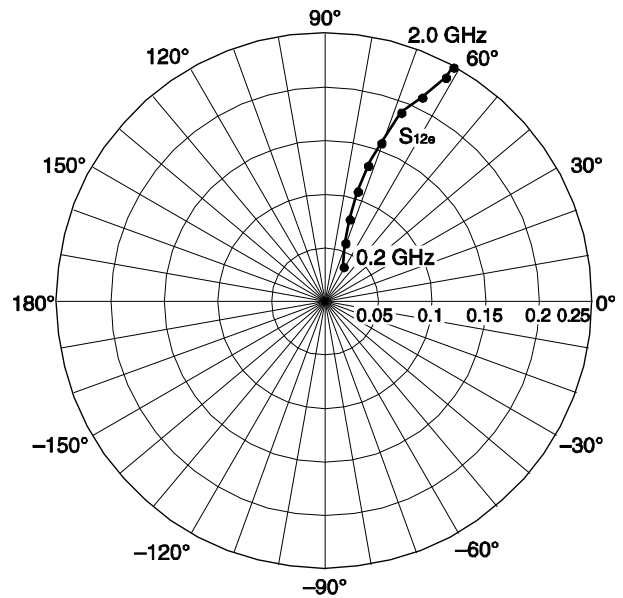
S_{21e}-FREQUENCY

CONDITION : V_{CE} = 10 V, I_c = 20 mA



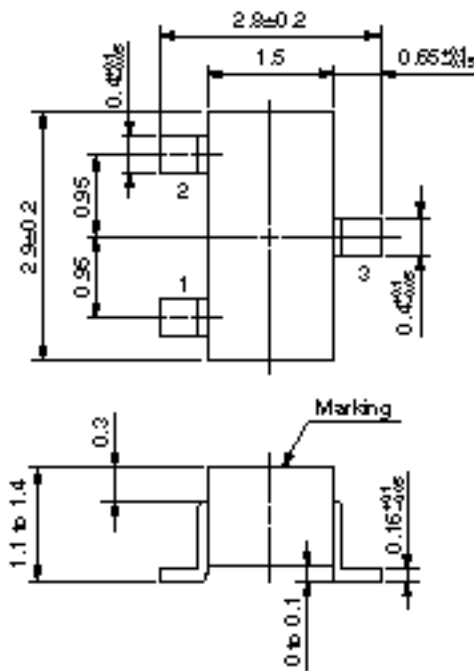
S_{12e}-FREQUENCY

CONDITION : V_{CE} = 10 V, I_c = 20 mA



PACKAGE DIMENSIONS

3-PIN MINIMOLD (UNIT: mm)



PIN CONNECTIONS

- 1. Emitter
- 2. Base
- 3. Collector

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M8E 00.4-0110

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